

650V SiC Schottky Diode

Amp+[™] Features

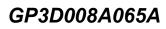
- Unipolar rectifier with surge current
- Zero reverse recovery current
- · Fast, temperature-independent switching
- Avalanche tested to 54mJ*

Amp+[™] Benefits

- Near zero switching loss
- Higher efficiency
- Smaller heat sink
- Easy to parallel

Amp+[™] Applications

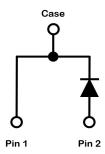
- Switch mode power supplies, UPS
- Power factor correction
- Output rectification
- General Purpose



VDC	650 V
Qc	21 nC
I _F	8 A
T _j ,max	175 °C







Part #	Package	Marking
GP3D008A065A	TO-220-2L	3D008A065



Maximum Ratings, at T_i=25 °C, unless otherwise specified

Characteristics	Symbol	Conditions	Values	Unit	
		T _c =25 °C, T _j =175 °C	27		
Continuous forward current	I _{F**}	T _C =125 °C, T _j =175 °C	14	A	
		T _C =150 °C, T _j =175 °C	9		
Surge non-repetitive forward current		T _C =25 °C, t _p =8.3 ms	70	•	
sine halfwave	I _{FSM}	T _C =110 °C, t _p =8.3 ms	60	— A	
Non-repetitive peak forward current	I _{F,max}	T _C =25 °C, t _p =10 μs	580	A	
i ² t value	∫i²dt	T _C =25 °C, t _p =8.3 ms	20	— A ² s	
		T _C =110 °C, t _p =8.3 ms	15		
Repetitive peak reverse voltage	V _{RRM}	T _j =25 °C	650	V	
Diode <i>dv/dt</i> ruggedness	dv/dt	Turn-on slew rate, repetitive	200	V/ns	
Power dissipation	P _{tot**}	T _C =25 °C	102	W	
Operating junction & storage temperature	T _j , T _{storage}	Continuous	-55175	°C	
Soldering temperature	T _{solder}	Wave soldering leads	260	°C	
Mounting torque		M3 Screw	1	N-m	
Notes:	I	1			

Notes:

* EAS of 54 mJ is based on starting Tj = 25°C, L = 1.0 mH, IAS = 10.39 A, V = 50 V.

** Typical Rth_{JC} used

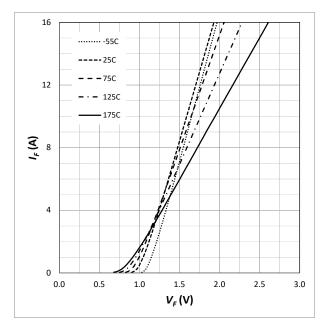
Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	Onit
DC blocking voltage	V _{DC}	T _j =25 °C	650	-	-	V
		I _F =8A, T _j =25 °C	-	1.45	1.60	
Diode forward voltage	V _F	I _F =8A, T _j =125 °C	-	1.57	-	V
		I _F =8A, T _j =175 °C	-	1.69	2.20	
		V _R =650V, T _j =25 °C	-	1	20	
Reverse current	I _R	V _R =650V, T _j =125 °C	-	8	-	μA
		V _R =650V, T _j =175 °C	-	31	200	
Total capacitive charge	Q _C	V _R =400V, T _j =25 °C	-	21	-	nC
		V _R =1V, f=1 MHz	-	336	-	
Total capacitance	С	V _R =200V, f=1 MHz	-	41	-	pF
		V _R =400V, f=1 MHz	-	34	-]

Electrical Characteristics, at T_j=25 °C, unless otherwise specified

Thermal Characteristics

Characteristics	Symbol Conditions		Values			Unit
	Symbol	Conditions	min.	typ.	max.	onic
Thermal resistance, junction-case	R _{thJC}	-	-	1.48	1.82	°C/W

Typical Performance





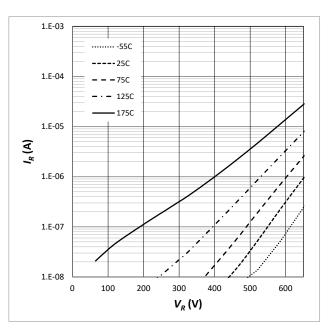
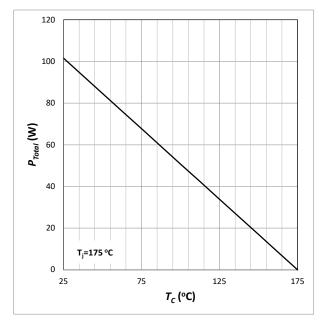


Fig. 2 Reverse Characteristics (parameterized on T_i)



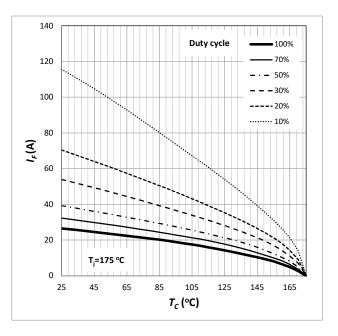
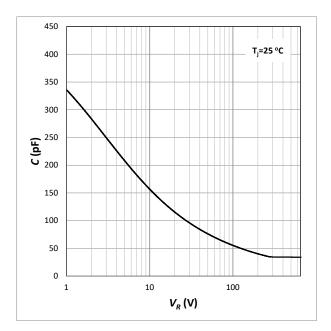


Fig. 3 Power Derating

Fig. 4 Current Derating



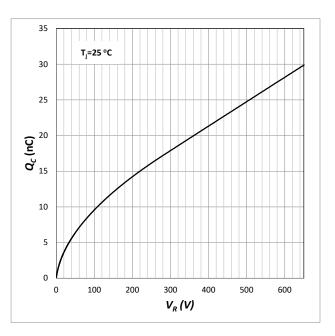
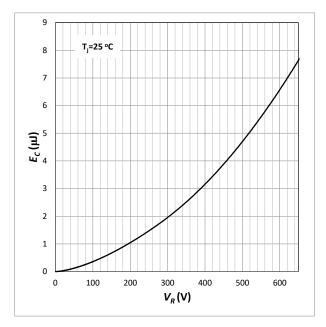


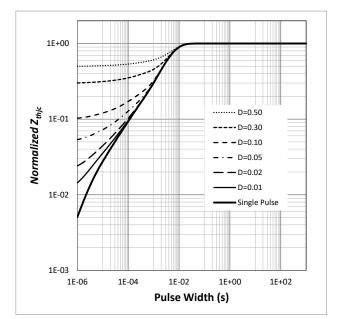
Fig. 5 Capacitance

Fig. 6 Capacitive Charge

Amp +™ 650V SiC Schottky Diode



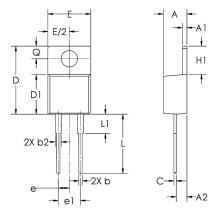


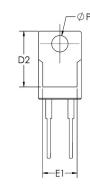


GP3D008A065A



Package Dimensions TO-220-2L





-A1

ł

H1

ł

Sum	Sum Millimeters		Inc	hes
Sym	Min	Max	Min	Max
А	3.56	4.83	0.140	0.190
A1	0.51	1.40	0.020	0.055
A2	2.03	2.92	0.080	0.115
b	0.38	1.02	0.015	0.040
b2	1.02	1.78	0.040	0.070
С	0.36	0.76	0.014	0.030
D	14.22	16.51	0.560	0.650
D1	8.38	9.40	0.330	0.370
D2	12.19	13.13	0.480	0.517
E	9.65	10.67	0.380	0.420
E1	6.86	8.89	0.270	0.350
е	2.54 BSC		.100 BSC	
e1	5.08 BSC		.200 BSC	
H1	5.84	6.86	0.230	0.270
L	12.57	14.73	0.495	0.580
L1	3.60	6.35	0.142	0.250
ØP	3.53	4.09	0.139	0.161
Q	2.54	3.43	0.100	0.135

Rev. 1, 4/30/2020

Notes

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented March, 2013. RoHS Declarations for this product can be obtained from the Product Documentation sections of www.SemiQ.com.

REACh Compliance

REACh substances of high concern (SVHC) information is available for this product. Since the European Chemicals Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact our office at SemiQ Headquarters in Lake Forest, California to insure you get the most up-to-date REACh SVHC Declaration. REACh banned substance information (REACh Article 67) is also available upon request.

SemiQ Inc., reserves the right to make changes to the product specifications and data in this document without notice. SemiQ products are sold pursuant to SemiQ's terms and conditions of sale in place at the time of order acknowledgement.

This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, or air traffic control.

SemiQ makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SemiQ assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using SemiQ products.

To obtain additional technical information or to place an order for this product, please contact us. The information in this datasheet is provided by SemiQ. SemiQ reserves the right to make changes, corrections, modifications, and improvements of datasheet without notice.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by SemiQ manufacturer:

Other Similar products are found below :

MA4E2039 D1FH3-5063 MBR0530L-TP MBR10100CT-BP MBR1545CT MMBD301M3T5G RB160M-50TR RB551V-30 BAS16E6433HTMA1 BAT 54-02LRH E6327 NSR05F40QNXT5G JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SK310-T SK32A-LTP SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP SK33B-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP ACDBA1100LR-HF ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G SB560 PMAD1108-LF SD103ATW-TP 1N5819T-G PDS1040Q-13 MBR3060FCTe3/TU